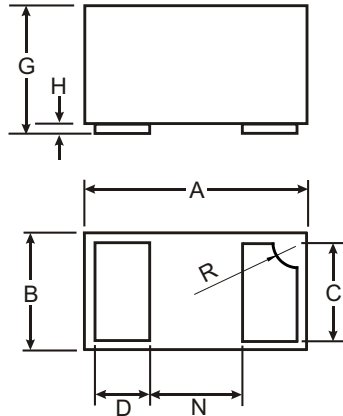


### Features

- Low Forward Voltage Drop
- Guard Ring Die Construction for Transient Protection
- Low Capacitance
- Lead Free By Design/RoHS Compliant (Note 1)**
- "Green" Device (Note 2)**
- Qualified to AEC-Q101 Standards for High Reliability**

### Mechanical Data

- Case: DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: Cathode Dot
- Terminals: Finish NiPdAu annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Code: LJ, Dot Denotes Cathode Side
- Ordering Information: See Last Page
- Weight: 0.001 grams



DFN1006-2			
Dim	Min	Max	Typ
A	0.95	1.075	1.00
B	0.55	0.675	0.60
C	0.45	0.55	0.50
D	0.20	0.30	0.25
G	0.47	0.53	0.50
H	0	0.05	0.03
N			0.40
R	0.05	0.15	0.10
All Dimensions in mm			

### Maximum Ratings @ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit
Maximum Peak Reverse Voltage	V <sub>RM</sub>	45	V
Reverse Voltage	V <sub>R</sub>	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Forward Current	I <sub>O</sub>	100	mA
Maximum (Peak) Forward Current	I <sub>FM</sub>	300	mA
Non-Repetitive Peak Forward Surge Current @ t = 10ms	I <sub>FSM</sub>	1	A
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-40 to +125	C

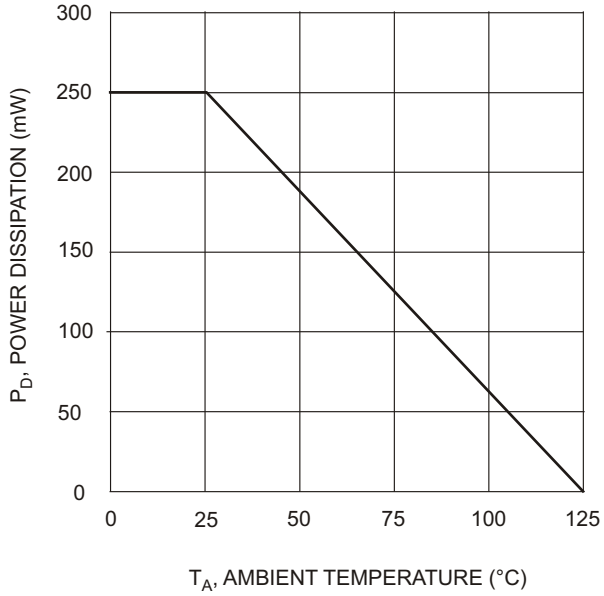
### Thermal Characteristics @ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>d</sub>	250	mW
Thermal Resistance, Ambient Air	R <sub>JA</sub>	400	C/W

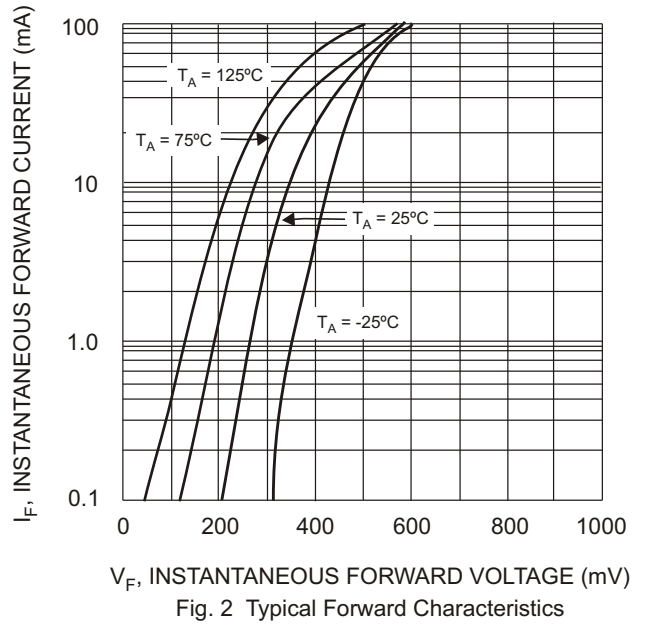
### Electrical Characteristics @ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Reverse Breakdown Voltage (Note 3)	V <sub>(BR)R</sub>	30			V	I <sub>R</sub> = 100 A
Forward Voltage Drop	V <sub>F</sub>		280 360 470 580	550 800	mV	I <sub>F</sub> = 1.0mA I <sub>F</sub> = 15mA I <sub>F</sub> = 50mA I <sub>F</sub> = 100mA
Reverse Current (Note 3)	I <sub>R</sub>			1.0	A	V <sub>R</sub> = 25V
Total Capacitance	C <sub>T</sub>		7	15	pF	V <sub>R</sub> = 10V, f = 1.0 MHz

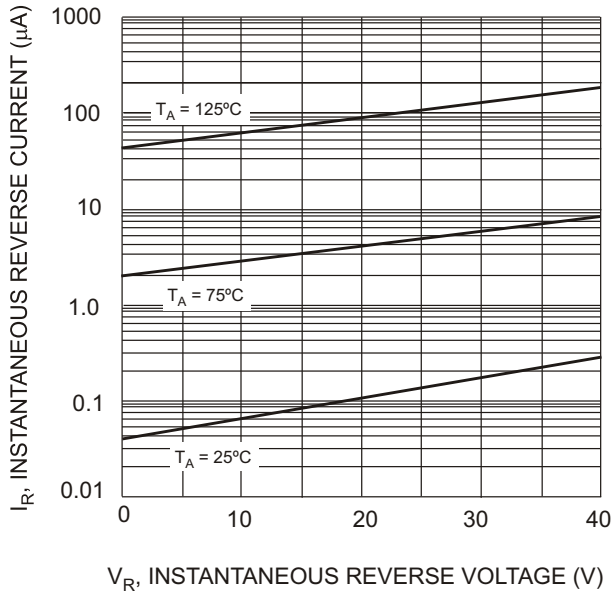
- Note:
1. No purposefully added lead.
  2. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Short duration pulse test used so as to minimize self-heating effect.



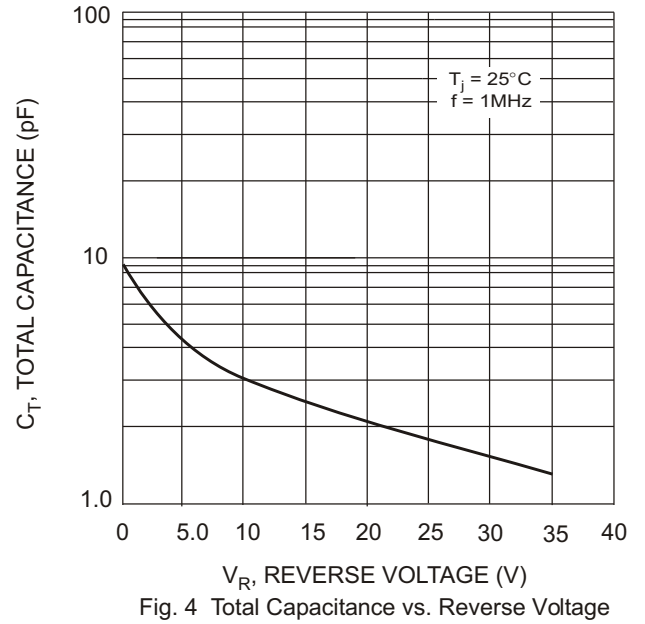
$T_A$ , AMBIENT TEMPERATURE (°C)  
Fig. 1 Power Derating Curve



$V_F$ , INSTANTANEOUS FORWARD VOLTAGE (mV)  
Fig. 2 Typical Forward Characteristics



$V_R$ , INSTANTANEOUS REVERSE VOLTAGE (V)  
Fig. 3 Typical Reverse Characteristics



$V_R$ , REVERSE VOLTAGE (V)  
Fig. 4 Total Capacitance vs. Reverse Voltage

**Ordering Information** (Note 4)

Device	Packaging	Shipping
SDM10U45LP-7	DFN1006-2	3000/Tape & Reel

Note: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**



LJ = Product Type Marking Code, Dot Denotes Cathode Side

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